NSN 5961-01-588-0433

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-588-0433 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.300 inches **Terminal Length:** Between 0.900 inches and 1.300 inches **Overall Diameter:** Between 0.115 inches and 0.165 inches **Function For Which Designed:** Rectifier **End Application:** 5999-01-529-8935; rectifier emi fltr **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 working peak reverse voltage **Current Rating Per Characteristic:** 125.00 amperes peak forward surge current **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Unleaded or surface mounted **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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